

2N5179
SILICON
NPN RF TRANSISTOR



TO-72 CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5179 type is a silicon NPN RF transistor, manufactured by the epitaxial planar process, designed for VHF/UHF amplifier, oscillator, and converter applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	20	V
Collector-Emitter Voltage	V_{CEO}	12	V
Emitter-Base Voltage	V_{EBO}	2.5	V
Continuous Collector Current	I_C	50	mA
Power Dissipation	P_D	200	mW
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D	300	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$
Thermal Resistance	θ_{JC}	0.58	$^\circ\text{C}/\text{mW}$
Thermal Resistance	θ_{JA}	0.87	$^\circ\text{C}/\text{mW}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=15\text{V}$		20	nA
I_{CBO}	$V_{CB}=15\text{V}, T_A=150^\circ\text{C}$		1.0	μA
BV_{CBO}	$I_C=1.0\mu\text{A}$	20		V
BV_{CEO}	$I_C=3.0\text{mA}$	12		V
BV_{EBO}	$I_E=10\mu\text{A}$	2.5		V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		0.4	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		1.0	V
h_{FE}	$V_{CE}=1.0\text{V}, I_C=3.0\text{mA}$	25	250	
h_{fe}	$V_{CE}=6.0\text{V}, I_C=2.0\text{mA}, f=1.0\text{kHz}$	25	300	
f_T	$V_{CE}=6.0\text{V}, I_C=5.0\text{mA}, f=100\text{MHz}$	900	2000	MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		1.0	pF
P_o	$V_{CB}=10\text{V}, I_E=12\text{mA}, f=500\text{MHz}$	20		mW
G_{pe}	$V_{CE}=6.0\text{V}, I_C=5.0\text{mA}, f=200\text{MHz}$	15		dB
NF	$V_{CE}=6.0\text{V}, I_C=1.5\text{mA}, f=200\text{MHz}, R_S=50\Omega$		4.5	dB
$t_b'C_C$	$V_{CB}=6.0\text{V}, I_C=2.0\text{mA}, f=31.9\text{MHz}$	3.0	14	ps

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TO-72 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.209	0.230	5.31	5.84
B (DIA)	0.175	0.195	4.45	4.95
C	-	0.030	-	0.76
D	0.170	0.210	4.32	5.33
E	0.500	-	12.70	-
F (DIA)	0.016	0.019	0.41	0.48
G (DIA)	0.100		2.54	
H	0.050		1.27	
J	0.036	0.046	0.91	1.17
K	0.028	0.048	0.71	1.22

TO-72 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector
- 4) Case

MARKING:

FULL PART NUMBER

R1 (8-May 2013)

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